N-Channel Junction Silicon FET



2SK3557

Low-Noise HF Amplifier Applications

Applications

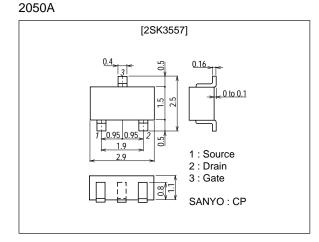
- AM tuner RF amplifier.
- Low noise amplifier.

Features

- Large |yfs|.
- Small Ciss.
- Ultrasmall-sized package permitting 2SK3557applied sets to be made smaller and slimer.
- Ultralow noise figure.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSX		15	V
Gate-to-Drain Voltage	VGDS		-15	V
Gate Current	IG		10	mA
Drain Current	۱D		50	mA
Allowable Power Dissipation	PD		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Symbol Conditions	Ratings			Unit
Farameter	Symbol		min	typ	max	Unit
Gate-to-Drain Breakdown Voltage	V(BR)GDS	IG=-10μΑ, V _{DS} =0	-15			V
Gate Cutoff Current	IGSS	V _{GS} =-10V, V _{DS} =0			-1.0	nA
Cutoff Voltage	V _{GS} (off)	V _{DS} =5V, I _D =100μA	-0.3	-0.7	-1.5	V

Marking : IR

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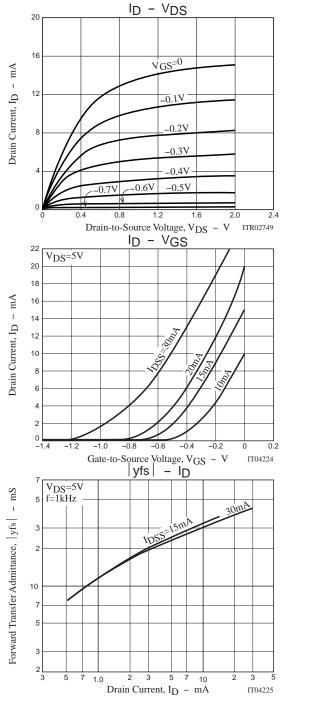
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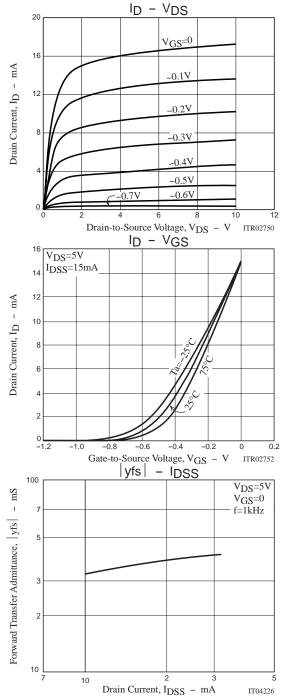
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

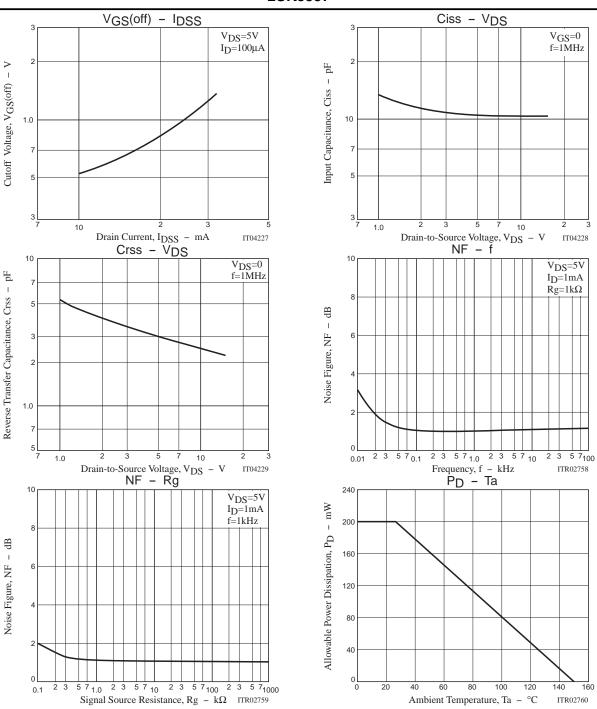
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Drain Current	IDSS	VDS=5V, VGS=0	10*		32*	mA
Forward Transfer Admittance	yfs	V _{DS} =5V, V _{GS} =0, f=1kHz	24	35		mS
Input Capacitance	Ciss	VDS=5V, VGS=0, f=1MHz		10.0		pF
Reverse Transfer Capacitance	Crss	V _{DS} =5V, V _{GS} =0, f=1MHz		2.9		pF
Noise Figure	NF	$V_{DS}=5V$, Rg=1k Ω , ID=1mA, f=1kHz		1.0		dB

*The 2SK3557 is classified by IDSS as follows : (unit : mA)

Rank	6	7
IDSS	10.0 to 20.0	16.0 to 32.0







160

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